April 2007



SEMICONDUCTOR

# FFPF08H60S Hyperfast 2 Rectifier

### Features

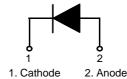
- High Speed Switching (t<sub>rr</sub>=45ns(Max.) @ I<sub>F</sub>=8A)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- Low Forward Voltage( V<sub>F</sub>=2.1V(Max.) @ I<sub>F</sub>=8A )

# Applications

- General Purpose
- Switching Mode Power Supply
- · Free-wheeling diode for motor application
- Power switching circuits

# **Pin Assignments**





8A, 600V Hyperfast 2 Rectifier

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tors.

The FFPF08H60S is hyperfast2 rectifier ( $t_{rr}$ =45ns(Max.) @ I<sub>F</sub>=8A). it has half the recovery time of ultrafast rectifier and is

silicon nitride passivated ion-implanted epitaxial planar con-

This device is intended for use as freewheeling/clamping rectifiers in a variety of switching power supplies and other power

swithching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power

switching circuits reducing power loss in the switching transis-

### 1. Cathode 2. Anode

### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V
V <sub>R</sub>	DC Blocking Voltage	600	V
I <sub>F(AV)</sub>	Average Rectified Forward Current @ $T_{C} = 105 \text{ °C}$	8	А
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	60	А
T <sub>J,</sub> T <sub>STG</sub>	Operating Junction and Storage Temperature	- 65 to +150	°C

### Thermal Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Мах	Units
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3.4	°C/W

### Package Marking and Ordering Information

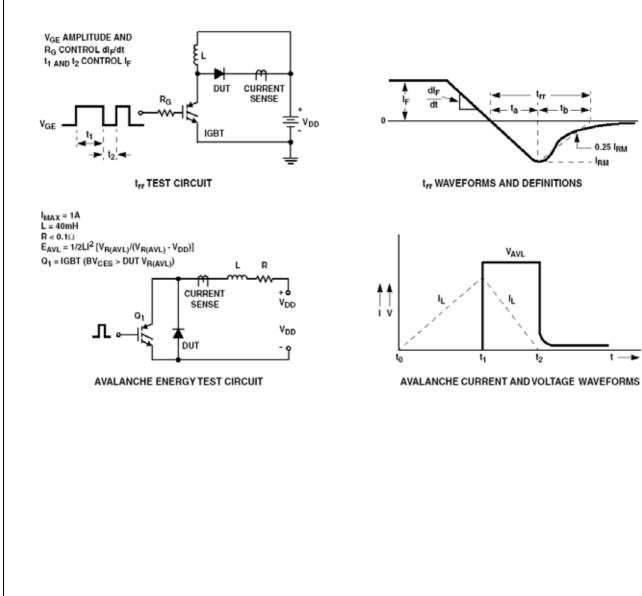
E08H60S EEPE08H60STU TO-220E - 50	Device Marking	Device	Package	Reel Size	Tape Width	Quantity
	F08H60S	FFPF08H60STU	TO-220F	-	-	50

Parameter	Conditions		Min.	Тур.	Max	Units
V <sub>FM</sub> <sup>1</sup>	I <sub>F</sub> = 8A I <sub>F</sub> = 8A	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	-	-	2.1 1.7	V V
I <sub>RM</sub> <sup>1</sup>	$V_{R} = 600V$ $V_{R} = 600V$	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	- -	-	100 200	μΑ μΑ
t <sub>rr</sub>	I <sub>F</sub> =1A, di/dt = 100A/μs, V <sub>CC</sub> = 30V I <sub>F</sub> =8A, di/dt = 100A/μs, V <sub>CC</sub> = 390V	T <sub>C</sub> = 25 °C T <sub>C</sub> = 25 °C	- -	-	35 45	ns ns
t <sub>a</sub> t <sub>b</sub> Q <sub>rr</sub>	I <sub>F</sub> =8A, di/dt = 100A/μs, V <sub>CC</sub> = 390V	$T_{C} = 25 \text{ °C}$	- - -	15 16 18.6	- - -	ns ns nC
W <sub>AVL</sub>	Avalanche Energy (L = 40mH)		20	-	-	mJ

#### Notes:

1. Pulse : Test Pulse width =  $300\mu$ s, Duty Cycle = 2%

# **Test Circuit and Waveforms**



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0.25 I<sub>RM</sub>

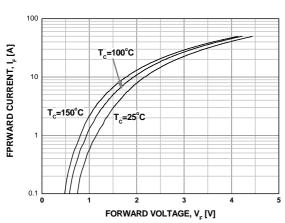
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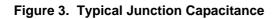
IRM

FFPF08H60S Hyperfast 2 Rectifier

# Typical Performance Characteristics T<sub>C</sub> = 25°C unless otherwise noted







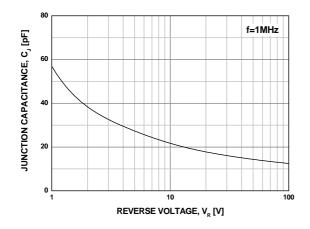


Figure 5. Typical Reverse Recovery Current

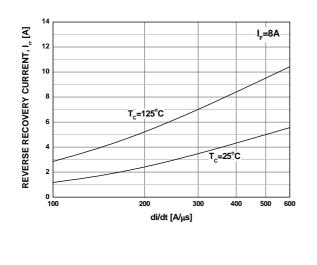


Figure 2. Typical Reverse Current

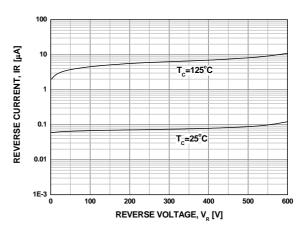
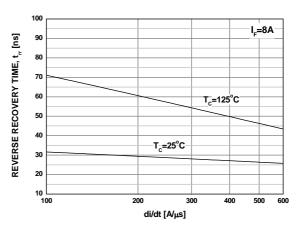
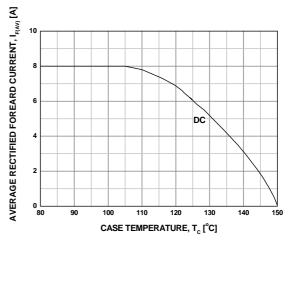
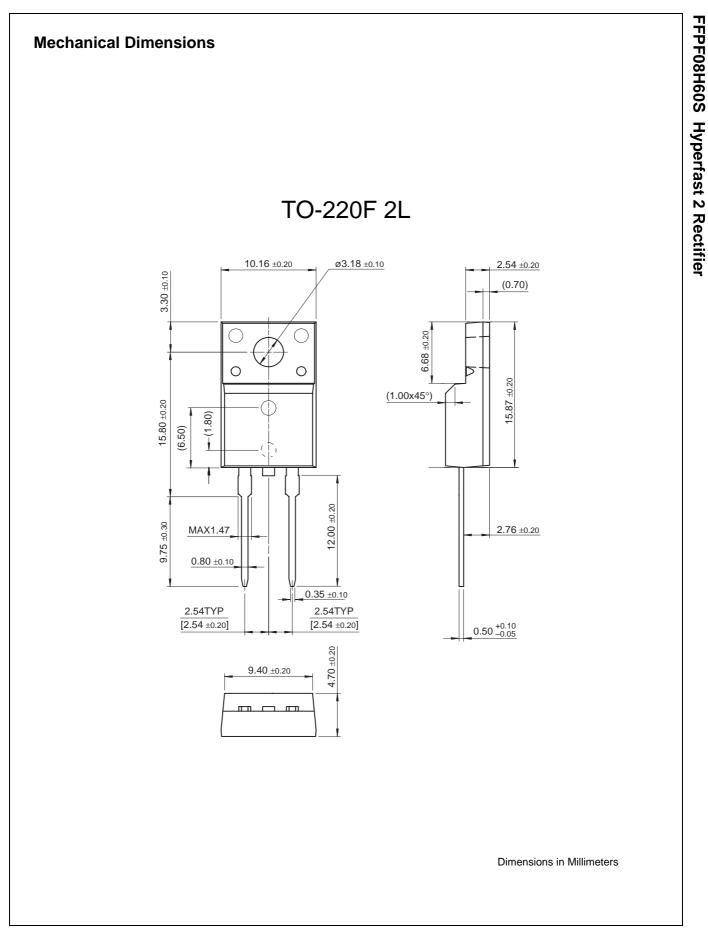


Figure 4. Typical Reverse Recovery Time











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Bottomless™	<i>i-Lo</i> ™	PowerTrench <sup>®</sup>	тм
Build it Now™	ImpliedDisconnect <sup>™</sup>	Programmable Active Droop <sup>™</sup>	U.
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